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# Performance Studies of the ATLASp<sub>ix</sub> HV-MAPS Prototype for Different Substrate Resistivities

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## Abstract

The *ATLASp<sub>ix</sub>* high-voltage monolithic active pixel sensor (HV-MAPS) was designed as a technology demonstrator for the ATLAS ITk Upgrade and the CLIC tracking detector. In this contribution new results from laboratory-based energy calibration measurements using fluorescence X-rays are presented for the matrix. These findings are complemented by new results from test-beam studies with inclined tracks, in which the active charge collection depth is determined.

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# Performance Studies of the ATLASp<sub>ix</sub> HV-MAPS Prototype for Different Substrate Resistivities

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**Abstract.** The *ATLASp<sub>ix</sub>* high-voltage monolithic active pixel sensor (HV-MAPS) was designed as a technology demonstrator for the ATLAS ITk Upgrade and the CLIC tracking detector. In this contribution new results from laboratory-based energy calibration measurements using fluorescence X-rays are presented for the *ATLASp<sub>ix</sub>-Simple* matrix. These findings are complemented by new results from test-beam studies with inclined tracks, in which the active charge collection depth is determined.

## 1. Introduction

The experimental conditions at future high-energy particle physics experiments, such as the High-Luminosity Large Hadron Collider (HL-LHC) [1] or the Compact Linear Collider (CLIC) [2], require highly performant detector systems to meet the foreseen physics goals. Due to the advances in the silicon sensor industry, all-silicon detector systems are regarded attractive options for future tracking detectors. Monolithic technologies combine both the sensor and the readout electronics on one chip, resulting in a reduced material budget compared to hybrid technologies. They are considered particularly suitable for large-area applications due to their cost efficiency and large-scale production capabilities of the CMOS imaging industry.

The *ATLASp<sub>ix</sub>* [3] was designed as a technology demonstrator for the ATLAS ITk upgrade [4] and the CLIC tracking detector [5]. It was manufactured in a commercial 180 nm HV-CMOS process on wafers with different substrate resistivities ranging from 20  $\Omega\text{cm}$  to 200  $\Omega\text{cm}$ . As a high-voltage monolithic active pixel sensor (HV-MAPS), it features a fully integrated readout. A high bias voltage of  $\mathcal{O}(100\text{ V})$  leads to large signals due to a large depleted volume, as well as a high electric field resulting in fast charge collection via drift. By removing bulk material from the backside, the sensors can be thinned to 50  $\mu\text{m}$ . The active matrix of the *ATLASp<sub>ix</sub>-Simple* consists of 25 columns and 400 rows of pixel cells with a pitch of  $130 \times 40\ \mu\text{m}^2$ , which are read out in a zero-suppressed triggerless column drain scheme. Each pixel consists of a deep N-well in a p-substrate forming the sensor diode. The N-well contains the in-pixel electronics comprising a charge-sensitive amplifier and a comparator. For each hit, the time-of-arrival (ToA) with a resolution of 10 bits and a binning of 16 ns, as well as the time-over-threshold (ToT) with a 6-bit resolution are recorded.

## 2. Energy Calibration with Fluorescence X-Rays

In order to perform an energy calibration of the detection threshold and the time-over-threshold (ToT) measurement, the *ATLASpdx\_Simple* samples were exposed to X-rays with well-defined energies. A commercial X-ray tube was used to excite fluorescence a target placed in front of the X-ray tube. By choosing different target materials (titanium, iron, copper), sharp  $K_\alpha$  peaks with well-defined energies were generated to which the *ATLASpdx\_Simple* were exposed.

### 2.1. Analysis Method

For each pixel of the matrix, the number of pixel hits per run of 20-40 s is plotted against the threshold. This yields a distribution as shown in Figure 1a, which can be described by a so-called s-curve:

$$f_s(x) = \frac{A}{2} \left( 1 - \operatorname{erf} \left( -\frac{x - \mu}{\sqrt{2}\sigma_n} \right) \right) + B, \text{ with the error function: } \operatorname{erf}(x) = \frac{2}{\sqrt{\pi}} \int_0^x e^{-t^2} dt, \quad (1)$$

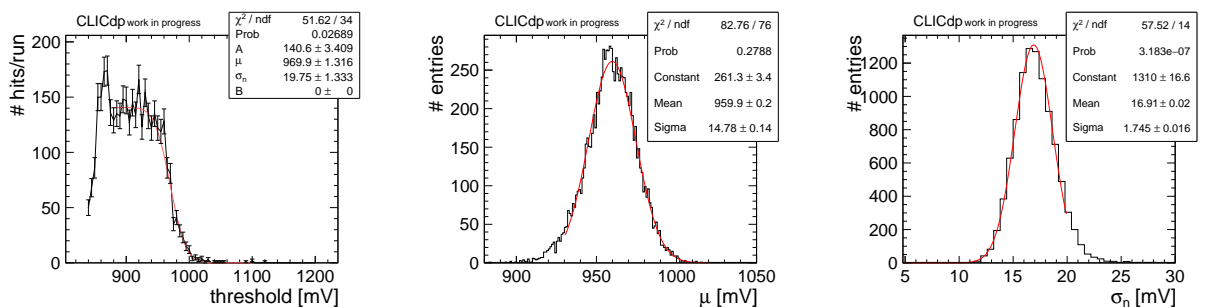
where  $A$  is a normalisation constant,  $\mu$  is the threshold value corresponding to the mean signal of the X-ray, and  $\sigma_n$  represents the pixel noise arising from fluctuations of the baseline and the threshold.  $B$  is an offset to account for a high-energy contamination of the measured spectrum from primary X-rays Compton-scattered at the target, which are observed for the low energy X-rays from titanium. For higher energies, it is set to zero. At very low thresholds, the hit count drops significantly due to an over-saturation of the readout caused by a strongly rising noise rate. Consequently, this region is excluded from the fit of the s-curve.

The resulting  $\mu$  and  $\sigma_n$  from the fit function are filled into histograms as shown in Figures 1b and 1c, which contain one entry from the fits to the s-curve of each pixel in the matrix. The histograms show normal distributions, which are fitted with a Gaussian to obtain the mean and the spread of each distribution:  $\bar{\mu} \pm \Delta\bar{\mu}$  and  $\bar{\sigma}_n \pm \Delta\bar{\sigma}_n$ . The non-gaussian tails visible on the left in Figure 1b and on the right in Figure 1c originate from noisy pixels.

### 2.2. Gain and Baseline

Since soft X-rays are absorbed completely, the amount of deposited energy  $E$  is well-defined and can be converted into the signal charge  $Q$  corresponding to the number of created electron-hole pairs. An average energy of 3.7 eV is required to generate one electron-hole pair [6]. Figure 2a shows the  $\bar{\mu}$  values obtained for the different X-ray targets. A first-order polynomial is fitted for all samples:

$$\bar{\mu} = g [\text{mV/keV}] \cdot E + b = g [\text{mV/1000e}] \cdot Q + b \quad (2)$$



(a) Exemplary s-curve fit for pixel (10,10).

(b) Distribution of the threshold  $\mu$  for all pixels fitted with a Gaussian.

(c) Distribution of the noise  $\sigma_n$  for all pixels fitted with a Gaussian.

Figure 1: Fit results obtained from s-curve fits for each pixel for a 200  $\Omega\text{cm}$  sample with fluorescent X-rays from an iron target (6.4 keV) at a bias voltage of  $-50$  V.

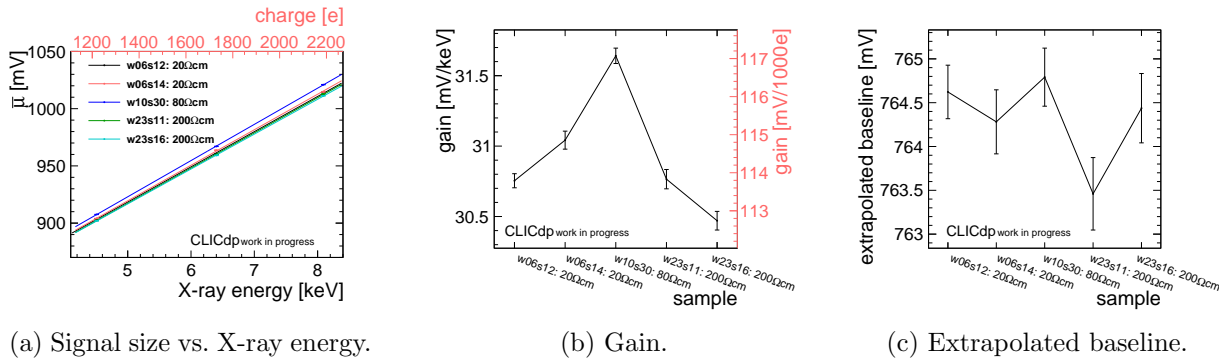


Figure 2: Signal vs. X-ray energy with a linear fit and the resulting gain (slope) and extrapolated baseline ( $y$ -intercept) for different samples and various fluorescent X-ray energies at a bias voltage of  $-50$  V. The error bars correspond to the statistical uncertainties on the fit parameters.

where  $b$  denotes the extrapolated baseline, i.e. the  $y$ -intercept of the polynomial. The slope  $g$  of the fit function can be interpreted as the signal gain, which is summarised in Figure 2b for all presented samples. Since no clear trend of the gain with the substrate resistivity can be seen, it can be concluded that the observed differences stem from sample-to-sample or wafer-to-wafer variations and are dominated by the electronics.

Figure 2c summarises the extrapolated baseline, i.e. the  $y$ -intercept of the linear fit functions for all samples. It is observed that it differs notably from the externally applied baseline of 800 mV. This effect is consistent with an expected voltage offset within the in-pixel comparator, which can be  $\mathcal{O}(\text{few } 10 \text{ mV})$  [7].

The inversion of Equation 2 can be used to determine the signal charge for a given threshold:

$$Q = \frac{\bar{\mu} - b}{g} \quad (3)$$

with the statistical uncertainty obtained by Gaussian error propagation.

Averaging over all samples a gain of  $\bar{g} = (114.5 \pm 1.5) \text{ mV}/1000e$  and an extrapolated baseline of  $\bar{b} = (764.3 \pm 0.6) \text{ mV}$  have been measured. It is important to note that the gain strongly depends on the chip configuration, in particular those parameters which regulate the current of the charge-sensitive amplifier in the pixel.

Using the gain as a conversion factor, the threshold dispersion  $\overline{\sigma}_{\mu}$  and the pixel noise  $\overline{\sigma}_n$  determined previously can now be translated into an equivalent charge. The standard deviation  $\sigma_{\mu} \sim 129 e^{-}$  is the threshold dispersion, i.e. the variation of the the detection threshold across the pixel matrix. The mean of  $\sigma_n \sim 148 e^{-}$  is the average pixel noise. For an energy deposition of 6.4 keV, this results in a signal-to-noise ratio of

$$SNR = \frac{\mu - b}{\sigma_n} \approx 11.0 \pm 1.2. \quad (4)$$

### 3. Test-beam Performance Measurements

Performance measurements of the *ATLASpix\_Simple* have been carried out at the DESY-II test-beam facility [8] using EUDET-type reference telescopes [9]. For the chosen electron beam momentum of 5.4 GeV, these yield a track pointing resolution of 2-5  $\mu\text{m}$ , depending on the plane spacing, which allows to study in-pixel effects. With an additional Timepix3 plane [10], a track time resolution of 1.1 ns is achieved. The *ATLASpix\_Simple* was controlled and read out with the Caribou system [11], and the reconstruction and analysis was carried out using the Corryvreckan framework [12].

### 3.1. Spatial and Time Resolution and Hit Detection Efficiency

Previous studies [13] have shown that the *ATLASpix-Simple* reaches a binary spatial resolution limited by its pixel pitch and a timing resolution down to 6.7 ns for the 200  $\Omega\text{cm}$  samples after a row-dependent delay and a timewalk correction. Lower substrate resistivities lead to a slower timing. Samples with all substrate resistivities can be operated at a high detection efficiency above 99 %, whereas the efficiency at high thresholds and low bias voltages remains larger for higher substrate resistivities.

### 3.2. Active Depth Determination

Inclined tracks are expected to lead to increased cluster sizes because a particle penetrates several adjacent pixels while passing through the detector material. As illustrated in Figure 3, this is dependent on the incidence angle  $\alpha$  as well as the pixel pitch and the active depth  $d_{\text{active}}$ . Here, the active depth refers to the depleted volume plus a possible additional layer below the depletion depth, from which charge may be collected by diffusion into the depletion region. In this simple geometrical model, the average cluster width in column/row direction is given by

$$\text{cluster width}_{\text{column/row}} = \frac{d_{\text{active}}}{\text{pitch}_{\text{column/row}}} \cdot \tan(\alpha). \quad (5)$$

In turn, a measurement of the angle dependence of the cluster size can be used to obtain an estimation of the active depth. This represents a simplified model, which neglects possible sub-threshold effects as well as lateral diffusion. This is an appropriate approximation for the *ATLASpix-Simple*, for which the mean cluster size is only marginally larger than one [14].

Figure 4 shows the mean cluster width in column direction plotted against the tangent of the rotation angle. Using equation 5, the active depth can be retrieved from the slope of a linear fit by dividing through the pixel pitch in the respective dimension. This yields an estimation of  $(60.3 \pm 1.9) \mu\text{m}$  at a bias voltage of  $-75 \text{ V}$ . The comparison with TCAD studies [15] suggests that the substrate resistivity lies around 300-400  $\Omega\text{cm}$  compared to the nominal value of 200  $\Omega\text{cm}$ . A possible range of 100-400  $\Omega\text{cm}$  is stated by the manufacturer due to deviations of the production parameters from the standard process [16].

## 4. Conclusions

It was shown that an X-ray based calibration is crucial for the the conversion of the detection threshold and noise from an applied voltage to equivalent charge. A higher substrate resistivity yields a higher efficiency and a better time resolution. The determination of the active depth

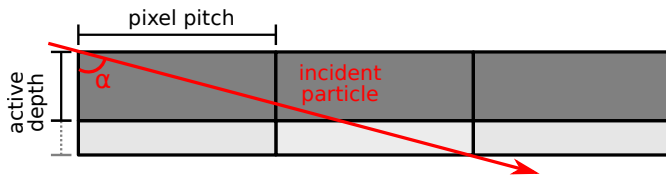


Figure 3: Schematic drawing of the track incidence angle dependence on the expected cluster size.

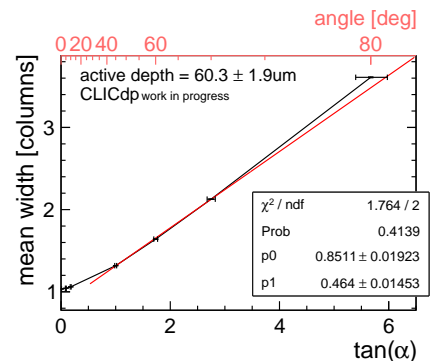


Figure 4: Angle dependence of the mean cluster size in column direction with a linear fit to extract the depletion depth.

implies that the substrate resistivity exceeds  $200\ \Omega\text{cm}$  in accordance with TCAD simulations [15].

The obtained results confirm that HV-MAPS is a suitable technology for future tracking detectors. It is now also investigated as a candidate technology for other experiments such as the MightyTracker Project for the LHCb Upgrades Ib and II [17].

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